NSN 5961-00-866-3189

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-866-3189 **Inclosure Material:** Glass **Overall Length:** Between 0.230 inches and 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.085 inches and 0.107 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 reverse voltage, peak **Current Rating Per Characteristic:** 5.00 amperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 170.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 80131-release2998 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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